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Charge-Pump White LED Driver

Features

- 3.0V to 6.5V input voltage range
- Dual mode operation; 1x and 1.5x
- Fixed 4.5V output with initial accuracy of ± 2%
- Supports up to 180mA (@4V) output
- High efficiency at both high and low input voltage
- Low external parts count, requires no inductor
- PWM brightness control via the ENA pin
- Selectable 262kHz or 650kHz switching frequency
- Low shutdown current of <1µA
- Soft start prevents excessive inrush current
- Over-temperature and over-current protection
- Low output ripple (<1%), low EMI
- Input protection provides superior ESD rating, requiring only standard handling precautions
- TDFN-10 or MSOP-10 package
- Optional RoHS compliant lead free package

Applications

- Drive white LEDs to backlight color LCDs
- Drive white or RGB LEDs for camera flash
- Cellular phones
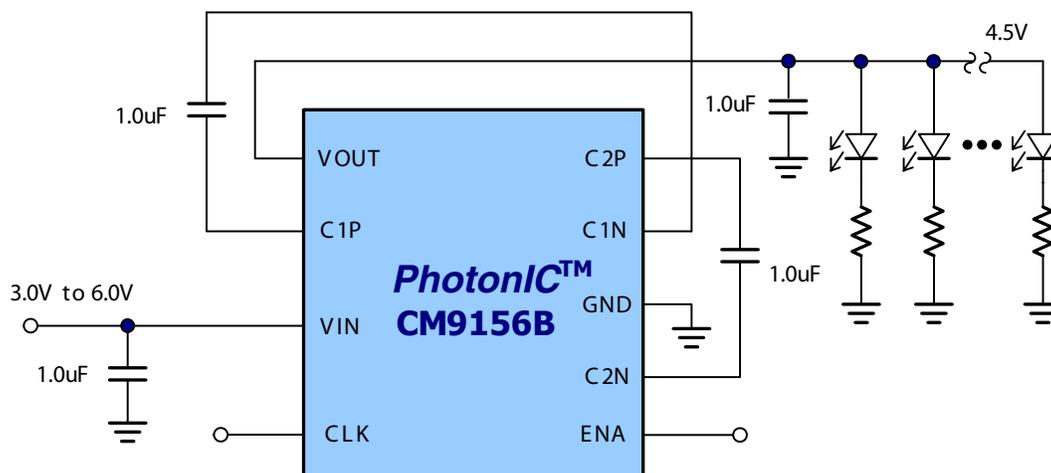- MP3 players
- PDAs, GPS

Product Description

CM9156B is an efficient 1.5x switched capacitor (charge pump) regulator ideal for white LED applications. It has a regulated 4.5V, 120mA output, capable of driving up to six parallel white LEDs. With a typical operating input voltage range from 3.0V to 6.0V, the CM9156B can be operated from a single-cell Li-Ion battery.

It features an efficient, 1.5x charge-pump circuit that uses only two 1.0µF ceramic bucket capacitors and two small capacitors for VIN and VOUT. The CM9156B offers a selectable switching frequency of 262kHz or 650kHz. The LED brightness can be adjusted by applying a PWM signal on the ENA pin.
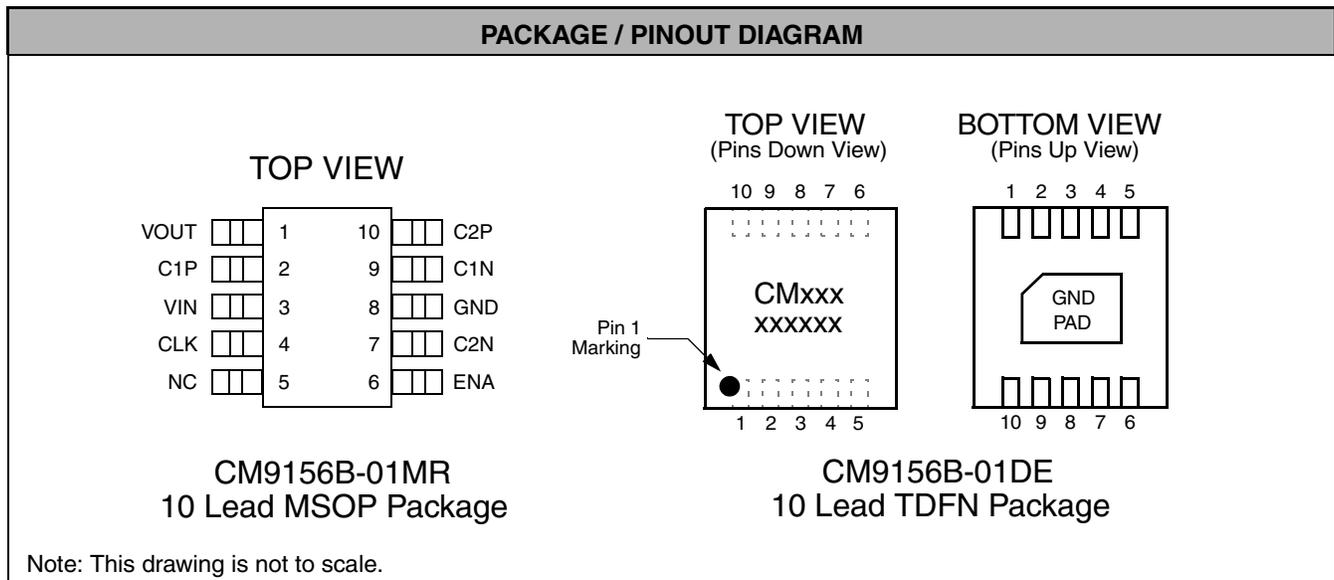
The CM9156B output voltage is regulated to 4.5V, ± 5% over the line and load ranges. Up 180mA of output current is available. The proprietary design architecture maintains high efficiency (> 80%), and at low V_{IN} provides longer battery life. With a high V_{IN}, or when the adapter is powered, it provides cool reliable operation. It offers low output voltage ripple, typically less than 50mV. Internal over-temperature and over-current management provide short circuit protection.

The CM9156B is packaged in either a space saving 10-Lead TDFN or 10-Lead MSOP package. It can operate over the industrial temperature range of – 25 °C to 85 °C.

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Typical Application

Package Pinout

PACKAGE / PINOUT DIAGRAM

TOP VIEW

VOUT	1	10	C2P
C1P	2	9	C1N
VIN	3	8	GND
CLK	4	7	C2N
NC	5	6	ENA

CM9156B-01MR
10 Lead MSOP Package

TOP VIEW
(Pins Down View)

10 9 8 7 6

CMxxx
xxxxxx

Pin 1
Marking

1 2 3 4 5

BOTTOM VIEW
(Pins Up View)

1 2 3 4 5

GND
PAD

10 9 8 7 6

CM9156B-01DE
10 Lead TDFN Package

Note: This drawing is not to scale.

Ordering Information

PART NUMBERING INFORMATION			
		Lead-free Finish	
Pins	**Package**	**Ordering Part Number[1]**	**Part Marking**
10	TDFN	CM9156B-01DE	
10	MSOP	CM9156B-01MR	

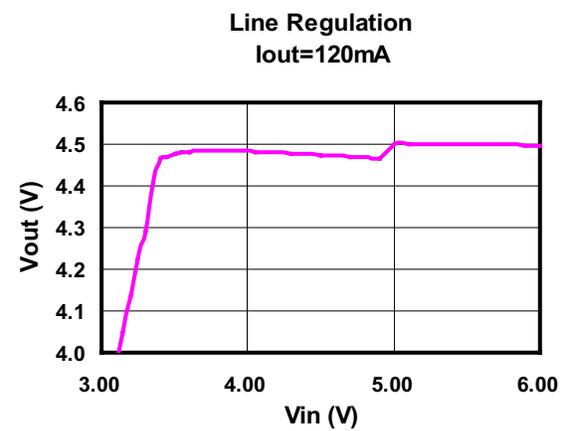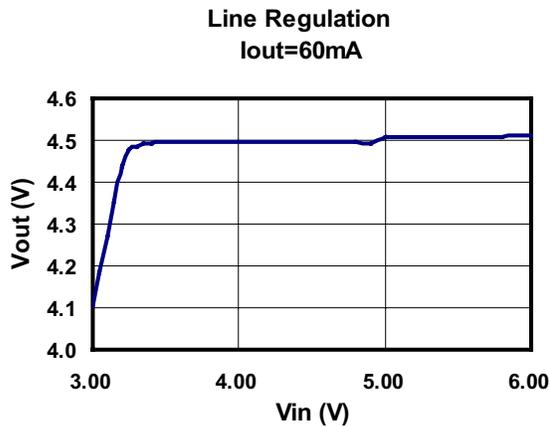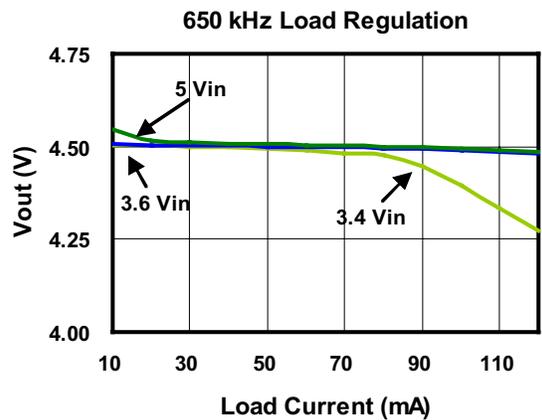Note 1: Parts are shipped in Tape & Reel form unless otherwise specified.
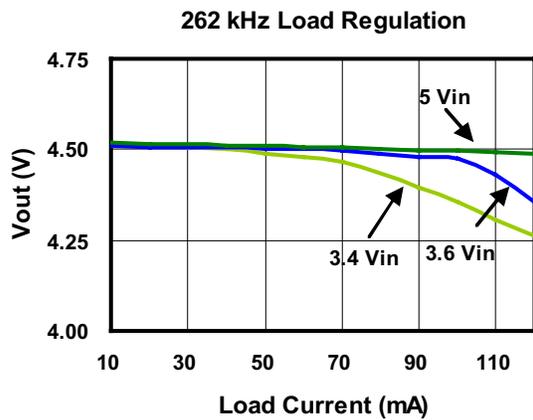
Specifications

ABSOLUTE MAXIMUM RATINGS		
PARAMETER	**RATING**	**UNITS**
ESD Protection (HBM)	± 2	kV
VIN to GND	[GND - 0.3] to +6.5	V

Pin Voltages
   V_{OUT} to GND
   C1P, C1N to GND
   ENA, CLK to GND
	[GND - 0.3] to +6.0
	[GND - 0.3] to +4.5
	[GND - 0.3] to +6.0
		V
		V
		V

Storage Temperature Range	-65 to +150	°C
Operating Temperature Range	-40 to +85	°C
Lead Temperature (Soldering, 10s)	300	°C

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Specifications (cont'd)

ELECTRICAL OPERATING CHARACTERISTICS							
SYMBOL	**PARAMETER**	**CONDITIONS**	**MIN**	**TYP**	**MAX**	**UNITS**
V_{IN}	VIN Supply Voltage		3.0		6.0	V
I_{SD}	Shut-Down Supply Current	ENA = 0		1		µA
I_Q	Quiescent Current	Fs = 262 kHz		800	1200	µA
		Fs = 650 kHz		1600	2500	µA
Charge-pump Circuit						
$V_{R\ LOAD}$	Load Regulation	Fs = 262 kHz or 650 kHz, Iout = 0 mA to 120 mA, Vin = 3.2V to 6.5V	4.2	4.5	4.7	V
		Iout = 0 mA to 90 mA, Vin = 3.0V to 3.2V	4.0	4.1	4.2	V
$V_{R\ LIN}$	Line Regulation	Iout = 60 mA, Vin = 3.2V to 6.5V	4.4	4.5	4.6	V
		Vin = 3.0V to 3.2V	4.0	4.1	4.3	V
I_{OUT}	Output Current	Vout = 4.5V			120	mA
		Vout = 4.0V			180	mA
V_{OUTR}	Output Ripple Voltage	Fs = 262 kHz, Iout = 60 mA		50		mV
fs	Switching Frequency	CLK = 0		262		kHz
		CLK = 1		650		kHz
CLK						
	High Level Input Voltage		1.2			V
	Low Level Input Voltage				0.6	V
ENA						
V_{IH}	High Level Input Voltage		1.3			V
V_{IL}	Low Level Input Voltage				0.4	V
Protection						
I_{LIM}	Over-Current Limit			400	600	mA
T_{JSD}	Over-Temperature Limit			135		ºC
T_{HYS}	Over-Temperature Hysteresis			15		ºC

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Typical Performance Curves

$C_{IN}=C_{OUT}=C_1=C_2=1.0\mu F$, $T_A=25^oC$, unless specified

Efficiency

Iout=60mA

Efficiency

Iout=120mA

262 kHz Load Regulation

650 kHz Load Regulation

Line Regulation
Iout=60mA

Line Regulation
Iout=120mA
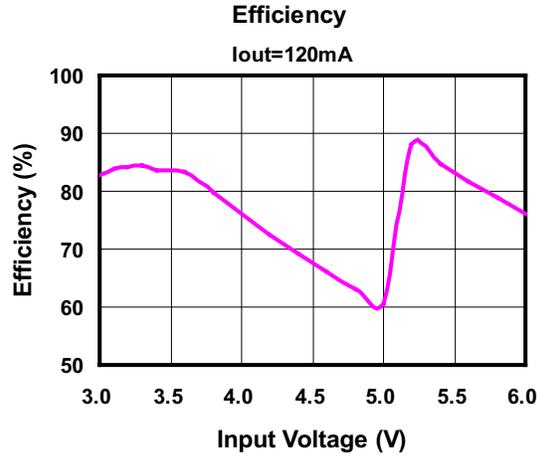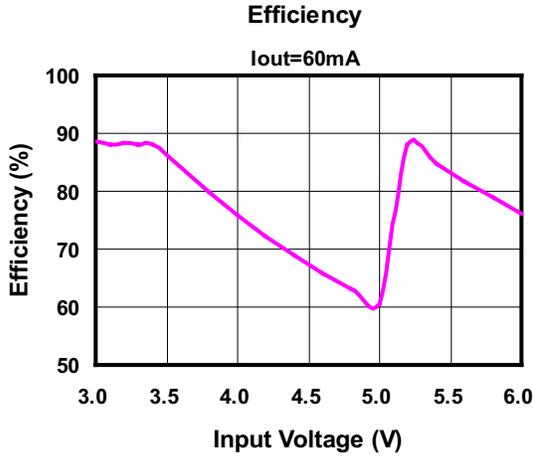
Typical Performance Curves (cont'd)

$C_{IN}=C_{OUT}=C_1=C_2=1.0\mu F$, $T_A=25^oC$, unless specified

No Load Input Current
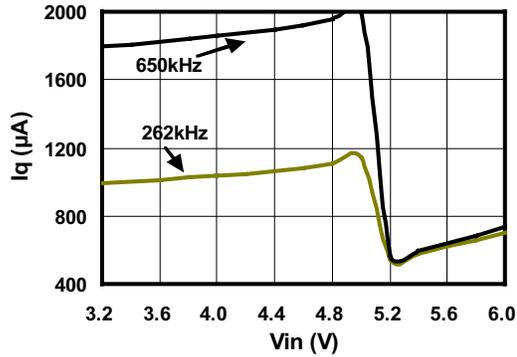
Vout vs. Temperature
Vin = 3.6V
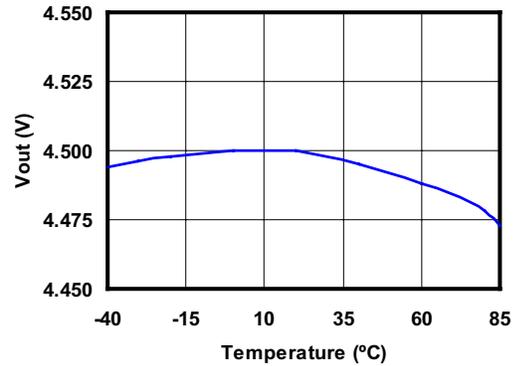
Switching Frequency - 262kHz
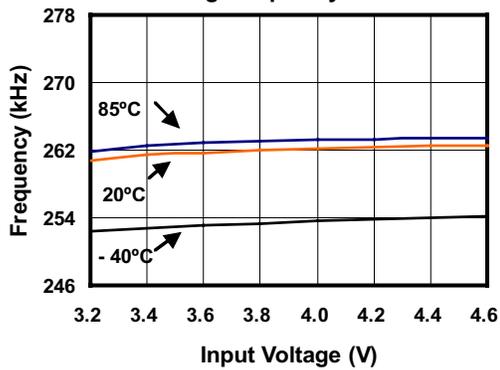
Switching Frequency - 650kHz

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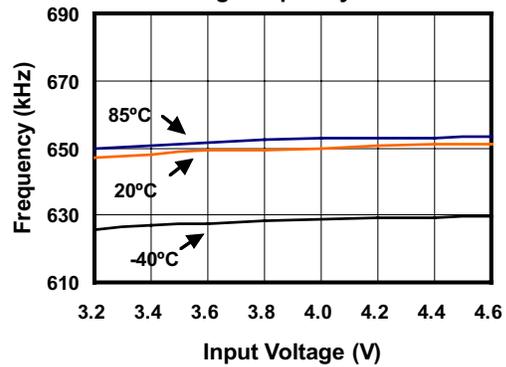
Typical Performance Curves (cont'd)

$C_{IN}=C_{OUT}=C_1=C_2=1.0\mu F$, $T_A=25^oC$, unless specified
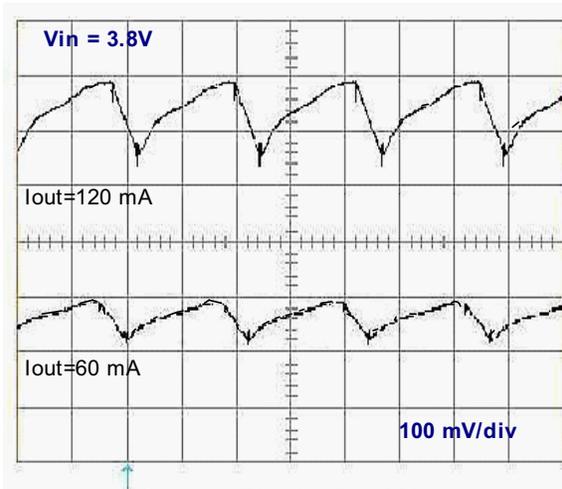
Output Ripple, 262 kHz
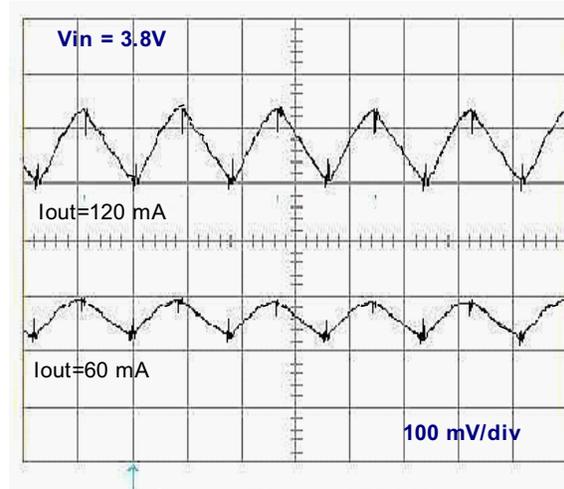
Output Ripple, 650 kHz
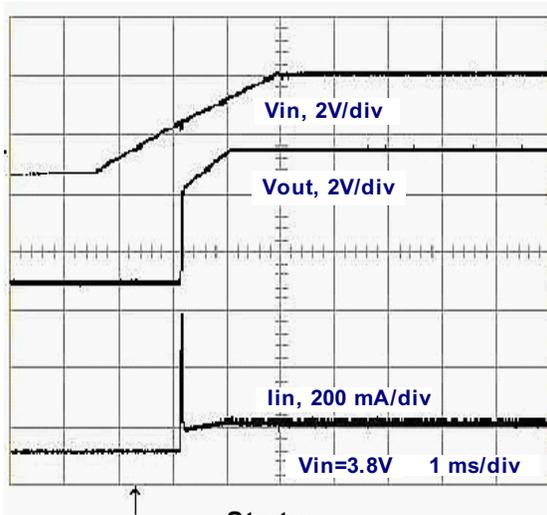
Startup

Frequency Selection Table

Switching Frequency	CLK1
262kHz	0
650kHz	1

Table 1: Frequency Selection

Functional Block Diagram
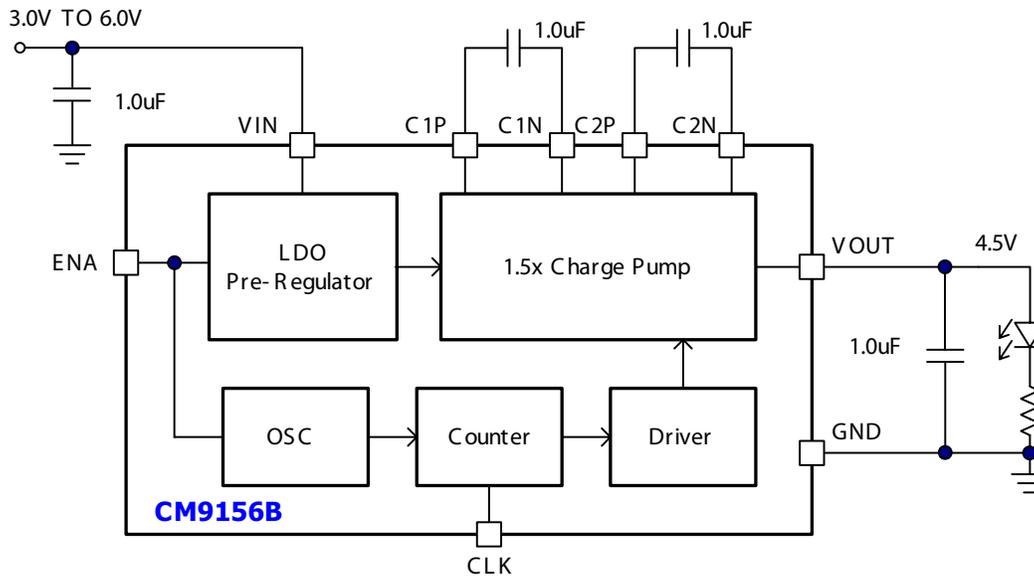
Pin Descriptions

PIN DESCRIPTIONS		
LEAD(s)	**NAME**	**DESCRIPTION**
1	VOUT	The regulated 4.5V output voltage pin. This pin requires a 1.0μF or larger ceramic capacitor to ground. This pin connects to the anodes of the LEDs.
2	C1P	This pin is the plus side of charge-pump bucket capacitor C1. Connect a 1.0μF ceramic capacitor with a voltage rating of 10V or greater between C1N and C1P.
3	VIN	Positive supply voltage input pin. This voltage should be between 3.0V and 6V. This pin requires a 1.0μF or larger ceramic capacitor to ground.
4	CLK	Pin for setting switching frequency (see Table 1 on page 6)
5	NC	Pin not connected.
6	ENA	Enable pin, active high. By applying a PWM signal to this pin, the LED brightness can be controlled.
7	C2N	This pin is the minus side of charge-pump bucket capacitor C2. Connect a 1.0μF ceramic capacitor between C2N and C2P.
8	GND	Ground pin.
9	C1N	This pin is the minus side of charge-pump bucket capacitor C1. Connect a 1.0μF ceramic capacitor between C1N and C1P.
10	C2P	This pin is the plus side of charge-pump bucket capacitor C2. Connect a 1.0μF ceramic capacitor between C2N and C2P.

Application Information

The CM9156B is a switched capacitor, charge pump voltage converter ideally suited for driving white LEDs to backlight or sidelight LCD color displays for portable devices, such as cellular phones, PDAs, and any application where small space and efficiency are critical. The CM9156B charge pump is the perfect driver for such portable applications, providing efficiency, compact overall size, low system cost and minimum EMI.

The CM9156B contains a linear low dropout (LDO) regulator followed by a 1.5x fractional charge pump that converts the nominal lithium-ion (Li-Ion) or lithium polymer battery voltage levels (3.6V) by a gain of 1.5 times and regulates the converted voltage to 4.5V, ±5%, enough to drive the forward voltage drop of white LEDs. The CM9156B requires only two external switched, or bucket, capacitors, plus an input and an output capacitor, providing for a compact, low profile design. In many applications, all these can conveniently be the same value of 1.0μF, commonly available in a compact 0805 surface mount package.

The CM9156B is intended for white LED applications, but it can drive most all types of LEDs with a forward voltage drop of less than 4V.

The LED current is determined by its series resistor, R_{LED}, and is approximately;

$$I_{LED} = \frac{4.5V - V_{FWD\_LED}}{R_{LED}}$$

Typical white LEDs have a forward voltage drop, V_{FWD_LED}, of 3.5V to 3.7V. Like single-junction devices, white LEDs often have poorly matched forward voltages. If the LEDs were put in parallel without a series resistor, the current in the paralleled branches would vary, resulting in non-uniform brightness. R_{LED}, in addition to setting the current, compensates for this variation by functioning as a ballast resistor, providing negative feedback for each paralleled LED.

CM9156B Operation

When a voltage exceeding the undervoltage lockout threshold (UVLO) is applied to the VIN pin, the CM9156B initiates a softstart cycle, typically lasting 1000μs. Softstart limits the inrush current while the out-

put capacitors are charged during the power-up of the device.

The input voltage, VIN, passes through an LDO pre-regulator that compares the output voltage to a precision bandgap reference. After the LDO, the charge pump boosts the LDO voltage by 1.5 times. A feedback circuit to the LDO monitors the output voltage, and when the output voltage reaches 4.5V, the LDO output will operate at about 3V, regulating the device output at 1.5 x 3V = 4.5V.

The charge pump uses two phases from the oscillator to drive internal switches that are connected to the bucket capacitors, C1 and C2, as shown in Figure 1. In the first switch position, the bucket capacitors are connected in series and each are charged from the LDO to a voltage of V_{LDO}/2. The next phase changes the switch positions so that C1 and C2 are put in parallel, and places them on top of V_{LDO}. The resulting voltage across C_{OUT} is then; $V_{LDO}+1/2V_{LDO} = 1.5$ x V_{LDO}.
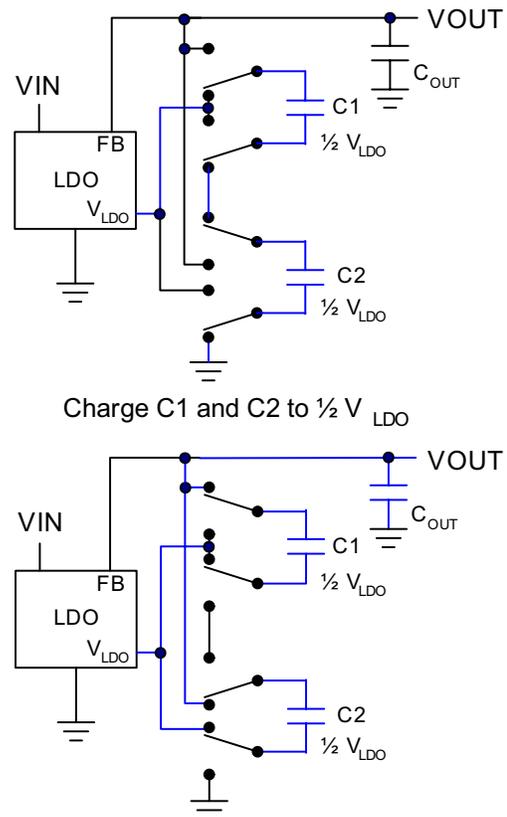

Charge C1 and C2 to ½ V $_{LDO}$

Figure 1. Switch operation

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Application Information (cont'd)

When the input voltage is greater then the output voltage, then all this sophistication, and the accompanying power loss, is unnecessary. The smart CM9156B knows this, and if the input voltage rises above 5V, the charge pump automatically disables, removing the voltage gain stage and the output is then provided directly through the LDO, regulated at 4.5V. This increases the efficiency and minimizes chip heating in this operating condition.

The CM9156B has over-temperature and over-current protection circuitry to limit device over-stress and failure during short circuit conditions. An overcurrent condition will limit the output current (approximately 400mA ~ 600mA) and will cause the output voltage to drop, until automatically resetting after removal of the excessive current. Over-temperature protection disables the IC when the junction is about 135 ºC, and automatically turns-on the IC when the junction temperature drops by approximately 15 ºC.

Efficiency

A conventional charge pump with a fixed gain of 2x will usually develop more voltage than is needed to drive paralleled white LEDs from Li-Ion sources. This excessive gain develops a higher internal voltage, reducing system efficiency and increasing battery drain in portable devices. A fractional charge pump with a gain of 1.5x is better suited for driving white LEDs in these applications.

The CM9156B charge pump automatically switches between 2 conversion gains, 1x and 1.5x, allowing high efficiency levels over a wide operating input voltage range. The 1x mode allows the regulated LDO voltage to pass directly through to the output when sufficient input voltage is available; the 1.5x charge pump is enabled only when the battery input is too low to sustain the output load.

At nominal loads, the switching losses and quiescent current are negligible. If these losses are ignored for simplicity, the efficiency, , for an ideal 1.5x charge pump can be expressed as the output power divided by the input power;

$$\eta \approx \frac{P_{OUT}}{P_{IN}}$$

For an ideal 1.5x charge pump, $I_{IN} = 1.5 \times I_{OUT}$, and the efficiency may be expressed as;

$$\frac{P_{OUT}}{P_{IN}} \approx \left(\frac{V_{OUT} \times I_{OUT}}{V_{IN} \times 1.5 \times I_{OUT}} \right) = \frac{V_{OUT}}{1.5 \times V_{IN}}$$

$$V_{OUT} = 4.5V, \qquad \therefore \quad \eta \approx \frac{4.5V}{1.5 \times V_{IN}}$$

The ideal 2x charge pump can be similarly expressed;

$$\frac{P_{OUT}}{P_{IN}} \approx \frac{4.5V}{2.0 \times V_{IN}}$$

In 1x mode, when the input voltage is above the output voltage, the part functions as a linear regulator and the ideal efficiency is simply Vout/Vin.

The typical conversion efficiency plots for these modes, with some losses, are shown in Figure 2.
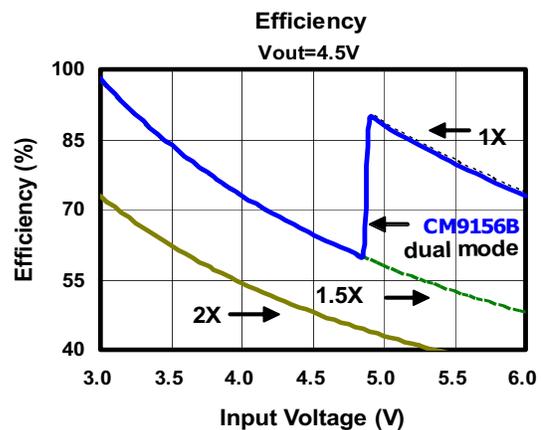

Figure 2. Ideal efficiency curves

As can be seen, the CM9156B, with 1x and 1.5x modes, has better efficiency in this application than a fixed 2x charge pump. At low battery voltages, the higher efficiency of the CM9156B charge pump's 1,5x gain reduces the battery drain. At higher input voltages, above 4.9V typically seen when the system is running off an AC adapter, the CM9156B, operating the

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Application Information (cont'd)

1x mode, has better efficiency than single mode 1.5x or 2x charge pumps, lowering the power dissipation for cooler circuit operation and long life.

CM9156B Design Example

Capacitor Selection

The external bucket capacitors will affect the output impedance of the converter, so surface-mount, low ESR ceramic capacitors are recommended. Tantalum and Aluminum capacitors should not be used because their ESR is too high. The ceramic dielectric must be stable over the operating temperature and voltage range, X7R or X5R dielectrics are recommended. In noise sensitive applications, output ripple can be further reduced by increasing the capacitance of the output capacitor. Reflected input ripple current depends on the impedance of the VIN source, which includes the PCB traces. Increasing the input capacitor will reduce this ripple. The input capacitor also affects the output voltage ripple. All the capacitors should be located close to the device for best performance.

Frequency Selection

The optimal switching frequency depends on the allowable system current draw, the load current, ripple and EMI requirements. The CM9156B's operating frequency choices are 262kHz or 650kHz. These two frequencies are selected by programming the CLK input. Refer to Table 1. The supply current for a charge pump is proportional to its switching frequency. A lower switching frequency allows reduced quiescent current for more efficient operation, but reduces the output current capability and in some cases, causes higher ripple. Higher frequencies are used when larger load currents are demanded.

The frequency is typically selected to achieve maximum efficiency while avoiding sensitive frequencies with the switching fundamental and its harmonics. The switching frequency can be set outside the critical frequency spectrums of cellular communications bandwidths. Once set, the switching frequency and its harmonics remain fixed, making filtering easy.

## LED Brightness Control
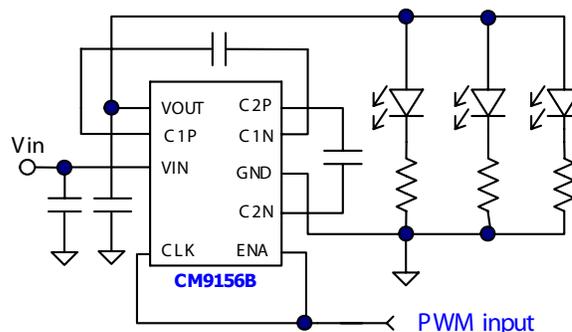
Figure 3. PWM brightness control, lowered quiescent current

Changes in ambient light often require the backlight display intensity to be adjusted, usually to conserve battery life. There are simple solutions to lowering the LED brightness when using the CM9156B.

A PWM signal applied to the ENA pin can be used to control the brightness, which is more efficient than other solutions that dissipate unwanted LED current in the series resistors. It also maintains the white LED color fidelity by avoiding color temperature variations that come with bias current changes. The LED intensity is determined by the PWM duty cycle, which can vary from 0% to 100%.

In the configuration shown in Figure 3, the brightness is controlled by the PWM signal applied to the LEDs. Decreased Duty Cycle will lower the LED brightness, See Figure 4 and Figure 5. The same signal is also applied to the CM9156B, reducing the charge pump switching frequency via the CLK control. When the PWM signal is high, CLK goes high, the operating frequency is 650kHz (refer to Table 1), and the LED current path is complete through the switch. When the PWM signal is low, the LED current is stopped as the switch turns off, and the switching frequency of the charge pump becomes 262kHz (CLK = 0). Operating the charge pump at the lower frequency lowers the quiescent current when the charge pump is operational (the input voltage below 5V).

Application Information (cont'd)
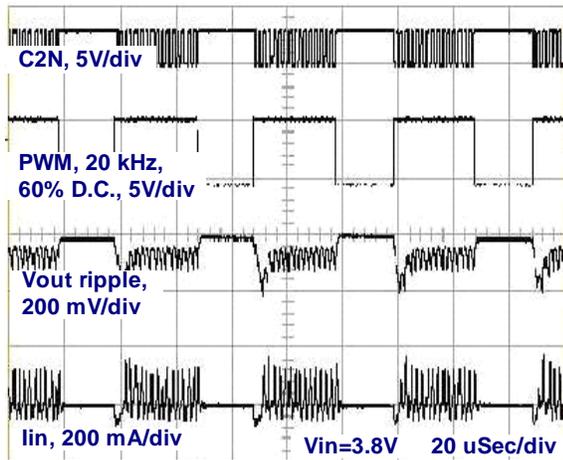
Figure 4. High brightness waveforms

The recommended PWM frequency is between 100 Hz and 20kHz. If a frequency of less then 100 Hz is used, flicker might be seen in the LEDs. The frequency should also be greater than the refresh rate of the TFT display. Higher frequencies will cause a loss of brightness control linearity. In addition, higher frequency can cause chromaticity shifts because the fixed rise and fall times of the PWM signal will shift the forward current.
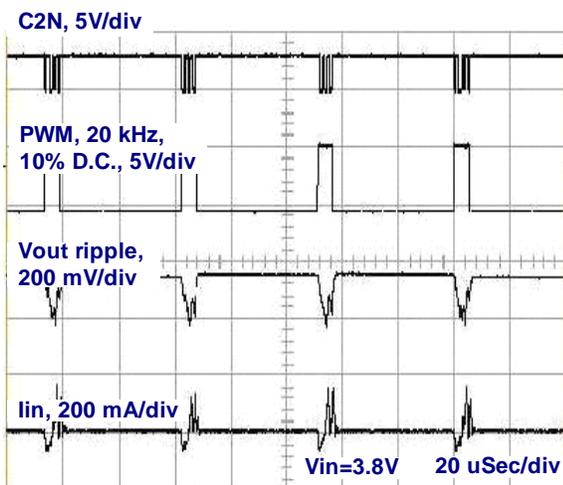
Figure 5. Low brightness waveforms

Camera Flash Application

Many smart phones and PDAs include a digital camera. These cameras typically utilize a WLED flash to illuminate the picture subject in low light conditions. The CM9156B is easily adapted to such an application. Figure 6 is a typical application using the CM9156B as a WLED flash driver, which is ideal for this application because it is capable of driving up to 180mA from a Li-ion battery. The One-shot is used to create a single pulse of a set duration to the ENA pin of the CM9156B.

The Flash LED modules shown here contain three matched WLEDs with a common anode and separated cathodes. The series resistor is chosen based on the forward drop of the module LEDs (typically 3.3V to 3.8V) and the number of parallel LEDs being driven.
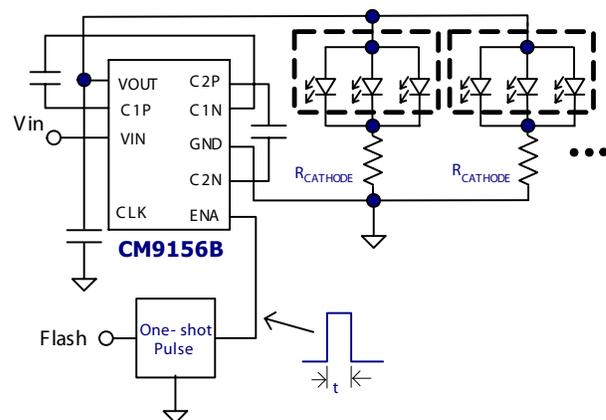
Figure 6. Camera flash application

Layout Guide

The charge pump is rapidly charging and discharging its external capacitors, so external traces to the capacitors should be made as wide and short as allowable to minimize inductance and high frequency ringing. The four capacitors should be located as close as practical to the charge-pump, particularly C1 and C2, which have the highest dv/dt. Connect ground and power traces to the capacitors through short, low impedance paths. Use a solid ground plane, ideally on the backside of the PCB, which should carry only ground potential. Connect the ground-side of Cin, Cout and the chip GND as close as practical. For best thermal performance, the exposed backside lead frame should be soldered to the PCB.

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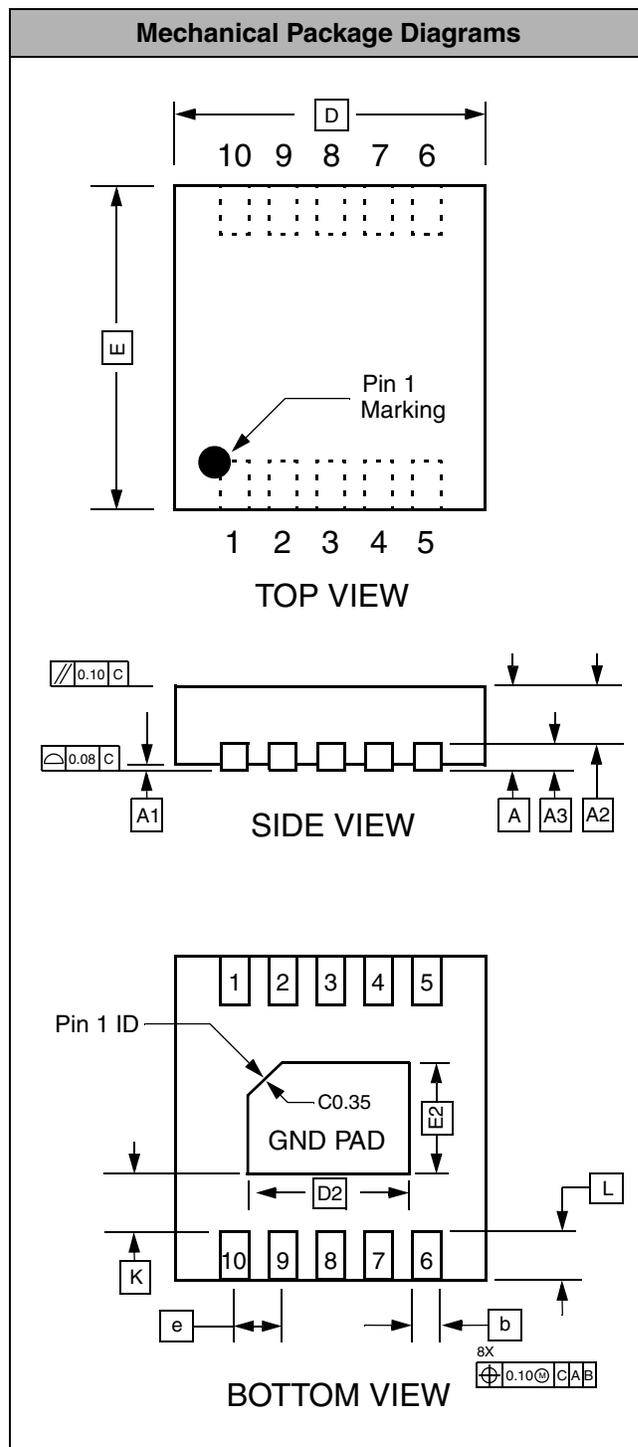
Mechanical Details

TDFN-10 Mechanical Specifications

Dimensions for the CM9156B packaged in a 10-lead TDFN package are presented below.

For complete information on the TDFN-10, see the California Micro Devices TDFN Package Information document.

PACKAGE DIMENSIONS						
Package	TDFN					
JEDEC No.	MO-229 (Var. WEED-3)=					
Leads	10					
Dim.	**Millimeters**			**Inches**		
	Min	**Nom**	**Max**	**Min**	**Nom**	**Max**
A	0.70	0.75	0.80	0.028	0.030	0.031
A1	0.00	0.02	0.05	0.000	0.001	0.002
A2	0.45	0.55	0.65	0.018	0.022	0.026
A3		0.20			0.008	
b	0.18	0.25	0.30	0.007	0.010	0.012
D		3.00			0.118	
D2	2.20	2.30	2.40	0.087	0.091	0.094
E		3.00			0.118	
E2	1.40	1.50	1.60	0.055	0.060	0.063
e		0.50			0.020	
K	1.30	1.50	1.70	0.051	0.060	0.067
L	0.20	0.30	0.40	0.008	0.012	0.016
# per tube	NA					
# per tape and reel	3000 pieces					
Controlling dimension: millimeters						

=This package is compliant with JEDEC standard MO-229, variation WEED-3 with exception of the "D2" and "E2" dimensions as called out in the table above.

Mechanical Package Diagrams

TOP VIEW

SIDE VIEW
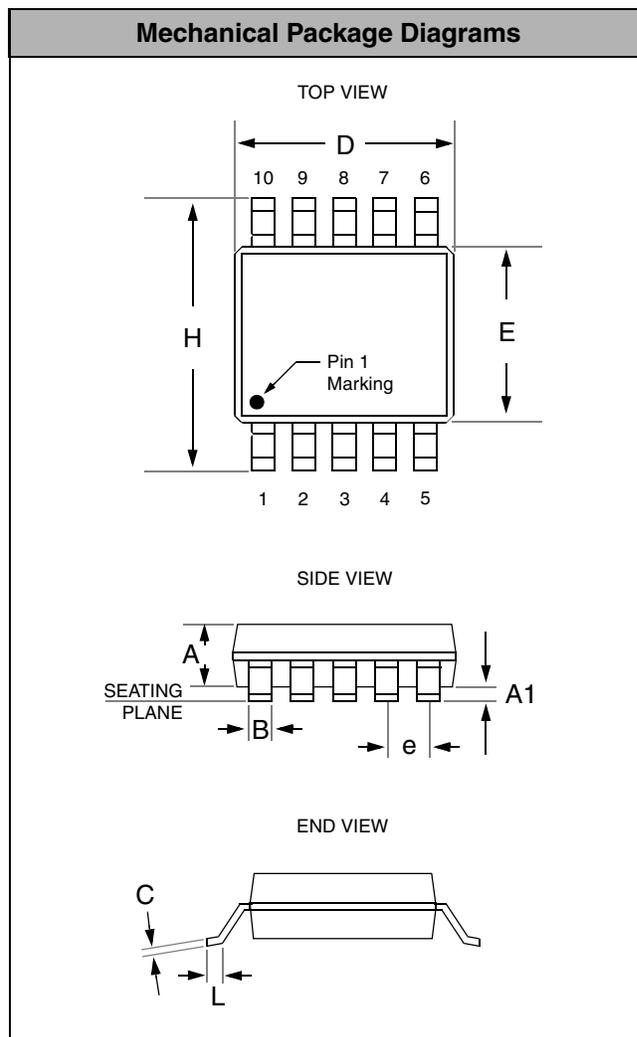
BOTTOM VIEW

Package Dimensions for 10-Lead TDFN

Mechanical Details (cont'd)

MSOP-10 Mechanical Specifications:

The CM9156B is supplied in a 10-pin MSOP. Dimensions are presented below.

For complete information on the MSOP-10, see the California Micro Devices MSOP Package Information document.

PACKAGE DIMENSIONS				
Package	MSOP			
Pins	10			
Dimensions	**Millimeters**		**Inches**	
	Min	**Max**	**Min**	**Max**
A	0.75	0.95	0.030	0.038
A1	0.05	0.15	0.002	0.006
B	0.17	0.33	0.007	0.013
C	0.15	0.30	0.006	0.018
D	2.90	3.10	0.114	0.122
E	2.90	3.10	0.114	0.122
e	0.50 BSC		0.0197 BSC	
H	4.90 BSC		0.193 BSC	
L	0.40	0.70	0.0157	0.0276
# per tape and reel	4000			
Controlling dimension: inches				

Mechanical Package Diagrams

TOP VIEW

SIDE VIEW

END VIEW

Package Dimensions for MSOP-10